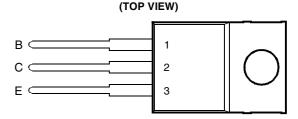
## 3OURNS®

- 80 W at 25°C Case Temperature
- 7 A Continuous Collector Current
- 10 A Peak Collector Current
- Maximum  $V_{CE(sat)}$  of 2 V at  $I_C = 5$  A
- I<sub>CEX(sus)</sub> 7 A at rated V<sub>(BR)CEO</sub>



**TO-220 PACKAGE** 

Pin 2 is in electrical contact with the mounting base.

MDTRACA

## This series is obsolete and not recommended for new designs.

#### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	TIP150		300	
Collector-base voltage (I <sub>E</sub> = 0)	TIP151	V <sub>CBO</sub>	350	V
	TIP152		400	
	TIP150		300	
Collector-emitter voltage (I <sub>B</sub> = 0)	TIP151	V <sub>CEO</sub>	350	V
	TIP152		400	
Emitter-base voltage		V <sub>EBO</sub>	8	V
Continuous collector current		I <sub>C</sub>	7	Α
Peak collector current (see Note 1)		I <sub>CM</sub>	10	Α
Continuous base current	I <sub>B</sub>	1.5	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)	$P_{tot}$	80	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W
Operating junction temperature range			-65 to +150	°C
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds	T <sub>L</sub>	260	°C	

- NOTES: 1. This value applies for t<sub>p</sub> ≤ 5 ms, duty cycle ≤ 10%.
  2. Derate linearly to 150°C case temperature at the rate of 0.64 W/°C.
  - 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.



#### electrical characteristics at 25°C case temperature

PARAMETER			TEST CONDITION	NS .	MIN TYP		MAX	UNIT
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> = 1 mA	I <sub>E</sub> = 0	TIP150 TIP151 TIP152	300 350 400			V
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 10 mA (see Note 4)	I <sub>B</sub> = 0	TIP150 TIP151 TIP152	300 350 400			V
I <sub>CEO</sub>	Collector-emitter cut-off current	V <sub>CE</sub> = 300 V V <sub>CE</sub> = 350 V V <sub>CE</sub> = 400 V	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$	TIP150 TIP151 TIP152			250 250 250	μА
I <sub>CEX(sus)</sub>	Collector-emitter sustaining current	V <sub>CLAMP</sub> = V <sub>(BR)CEO</sub>			7			Α
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 8 V	I <sub>C</sub> = 0				15	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 5 V$ $V_{CE} = 5 V$ $V_{CE} = 5 V$	$I_{C} = 2.5 A$ $I_{C} = 5A$ $I_{C} = 7 A$	(see Notes 4 and 5)	150 50 15			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	$I_B = 10 \text{ mA}$ $I_B = 100 \text{ mA}$ $I_B = 250 \text{ mA}$	$I_{C} = 1 A$ $I_{C} = 2 A$ $I_{C} = 5 A$	(see Notes 4 and 5)			1.5 1.5 2	V
V <sub>BE(sat)</sub>	Base-emitter saturation voltage	I <sub>B</sub> = 100 mA I <sub>B</sub> = 250 mA	$I_C = 2 A$ $I_C = 5 A$	(see Notes 4 and 5)			2.2 2.3	٧
V <sub>EC</sub>	Parallel diode forward voltage	I <sub>E</sub> = 7 A	I <sub>B</sub> = 0	(see Notes 4 and 5)			3.5	V
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 5 V	I <sub>C</sub> = 0.5 A	f = 1 kHz	200			
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 5 V	I <sub>C</sub> = 0.5 A	f = 1 MHz	10			
C <sub>ob</sub>	Output capacitance	V <sub>CB</sub> = 10 V	$I_{E} = 0$	f = 1 MHz			100	pF

NOTES: 4. These parameters must be measured using pulse techniques,  $t_p = 300 \mu s$ , duty cycle  $\leq 2\%$ .

#### thermal characteristics

PARAMETER			TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.56	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W
$C_{\thetaC}$	Thermal capacitance of case		0.9		J/°C

### inductive-load-switching characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t <sub>sv</sub>	Voltage storage time	$\mathbf{V}(clomp) = \mathbf{V}(PP)CEO$				3.9		μs
t <sub>si</sub>	Current storage time					4.7		μs
t <sub>rv</sub>	Voltage transition time		$I_{B(on)} = 250 \text{ mA}$	$R_{BE} = 47 \Omega$		1.2		μs
t <sub>ti</sub>	Current transition time					1.2		μs
t <sub>xo</sub>	Cross-over time					2.0		μs

<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>5.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

#### PARAMETER MEASUREMENT INFORMATION

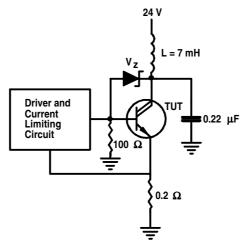


Figure 1. Functional Test Circuit

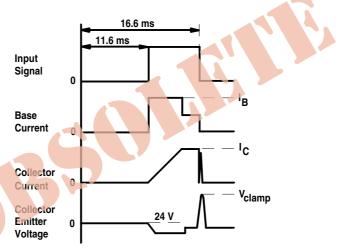


Figure 2. Functional Test Waveforms

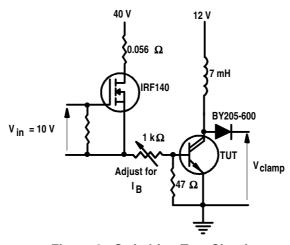
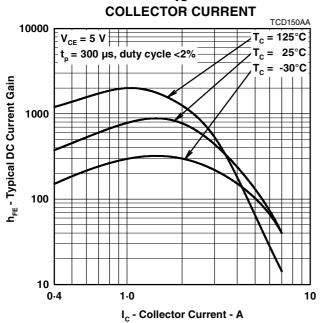


Figure 3. Switching Test Circuit

#### **TYPICAL CHARACTERISTICS**

# TYPICAL DC CURRENT GAIN vs



## Figure 4.

#### **COLLECTOR-EMITTER SATURATION VOLTAGE**

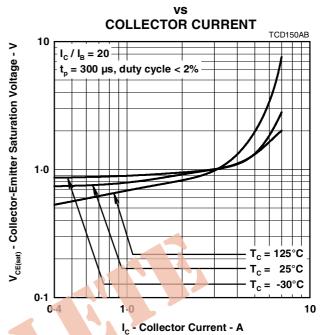
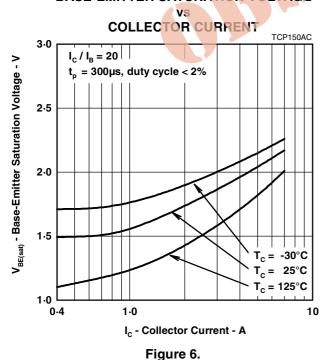
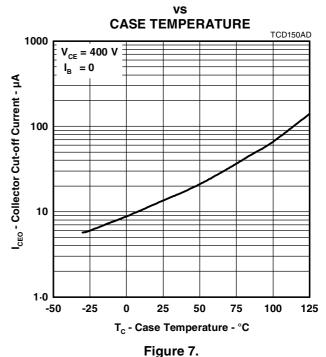


Figure 5.

#### BASE-EMITTER SATURATION VOLTAGE

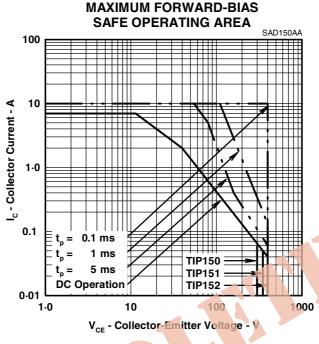


## **COLLECTOR CUT-OFF CURRENT**



#### PRODUCT INFORMATION

#### **MAXIMUM SAFE OPERATING REGIONS**



#### Figure 8.

#### THERMAL INFORMATION

#### MAXIMUM POWER DISSIPATION

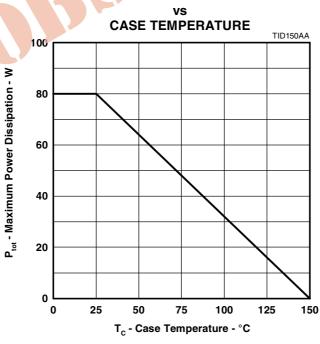


Figure 9.

#### PRODUCT INFORMATION